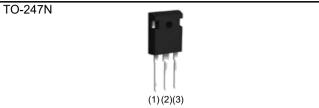


RGS80TS65HR

650V 40A Field Stop Trench IGBT

V _{CES}	650V
I _{C (100°C)}	40A
V _{CE(sat) (Typ.)}	1.65V
P _D	272W

Outline



Inner Circuit



- 1) Low Collector Emitter Saturation Voltage
- 2) Short Circuit Withstand Time 8µs
- 3) Qualified to AEC-Q101
- 4) Pb free Lead Plating ; RoHS Compliant

Application

Heater for Automotive

	(1) Gate (2) Collector (3) Emitter
--	--

Packaging Specifications

	Packaging	Tube
Туре	Reel Size (mm)	-
	Tape Width (mm)	-
	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGS80TS65

•Absolute Maximum Ratings (at T_c = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	$T_{\rm C}$ = 25°C	Ι _C	73	Α
Collector Current	T _C = 100°C	Ι _C	40	Α
Pulsed Collector Current		I _{CP} ^{*1}	120	Α
Dower Discinction	$T_{C} = 25^{\circ}C$	P _D	272	W
Power Dissipation	T _C = 100°C	P _D	136	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

*1 Pulse width limited by T_{jmax.}

•Thermal Resistance

Parameter	Symbol	Values			Unit
		Min.	Тур.	Max.	Onit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.55	°C/W

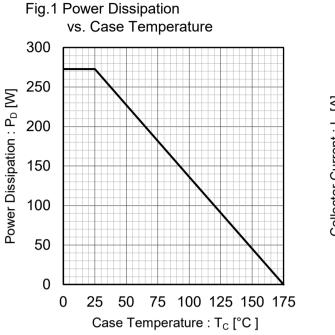
●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

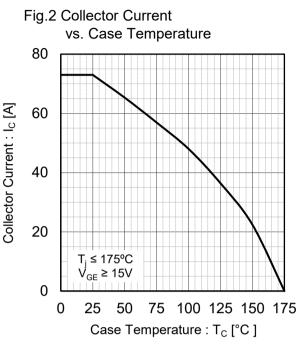
Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol		Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	Ι _C = 10μΑ, V _{GE} = 0V	650	-	-	V
		V _{CE} = 650V, V _{GE} = 0V,				
Collector Cut - off Current	I _{CES}	T _j = 25℃ Tj = 175℃ ^{*2}	-	-	10	μA
		Tj = 175°C ^{*2}	-	-	5	mA
Gate - Emitter Leakage Current	I _{GES}	V_{GE} = ±30V, V_{CE} = 0V	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	V _{CE} = 5V, I _C = 2.0mA	5.0	6.0	7.0	V
		I _C = 40A, V _{GE} = 15V,				
Collector - Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	T _j = 25°C	-	1.65	2.10	V
		T _j = 175°C	-	2.15	-	V

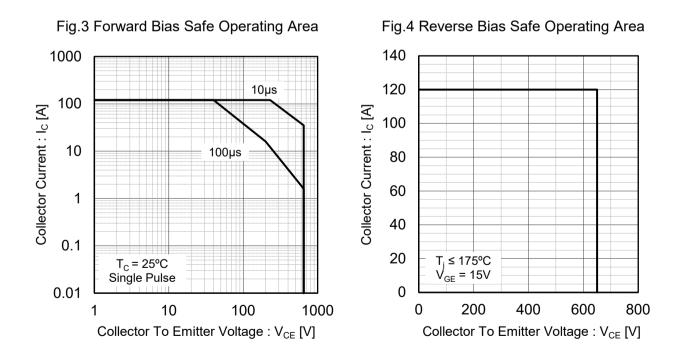
●IGBT Electrical Characteristics (at T_i = 25°C unless otherwise specified)

Parameter	Symbol Condition	Conditions	Values			1.1
		Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V,	-	1240	-	
Output Capacitance	C _{oes}	V _{GE} = 0V,	-	103	-	pF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	16	-	
Total Gate Charge	Qg	V _{CE} = 300V,	-	48	-	
Gate - Emitter Charge	Q _{ge}	I _C = 40A,	-	12	-	nC
Gate - Collector Charge	Q _{gc}	V _{GE} = 15V	-	19	-	
Turn - on Delay Time	t _{d(on)}		-	37	-	
Rise Time	t _r	I _C = 40A, V _{CC} = 400V, V _{GE} = 15V, R _G = 10Ω,	-	17	-	
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	112	-	ns
Fall Time	t _f	Inductive Load	-	96	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	1.05	-	mJ
Turn - off Switching Loss	E _{off}	,	-	1.03	-	
Turn - on Delay Time	t _{d(on)}		-	34	-	
Rise Time	t _r	$I_{C} = 40A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$ $T_{j} = 175^{\circ}C$ Inductive Load	-	28	-	ns
Turn - off Delay Time	t _{d(off)}		-	141	-	
Fall Time	t _f		-	150	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	1.43	-	m
Turn - off Switching Loss	E _{off}		-	1.47	-	mJ
		I _C = 120A, V _{CC} = 520V,				
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V,	FULL SQUARE			-
ouro oporaling / roa		R _G = 50Ω, T _j = 175°C				
Short Circuit Withstand Time	t _{sc}	V _{CC} ≤ 360V, V _{GE} = 15V, T _j = 25°C	8	-	-	μs
Short Circuit Withstand Time	t _{sc} *2	V _{CC} ≤ 360V, V _{GE} = 15V, T _j = 150°C	6	-	-	μs

*2 Design assurance without measurement







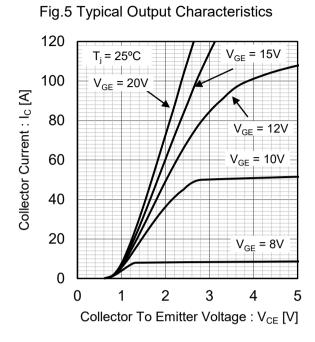


Fig.7 Typical Transfer Characteristics

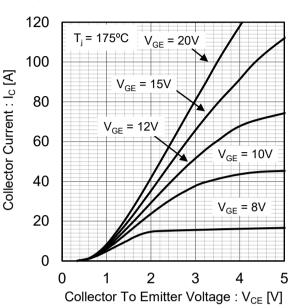
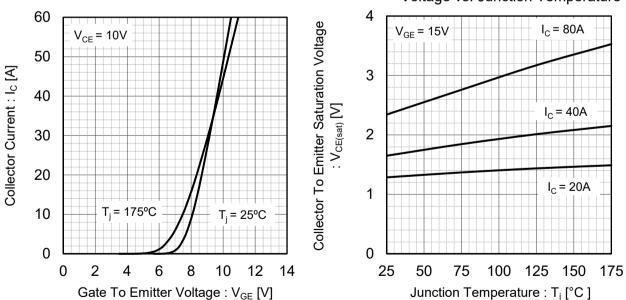
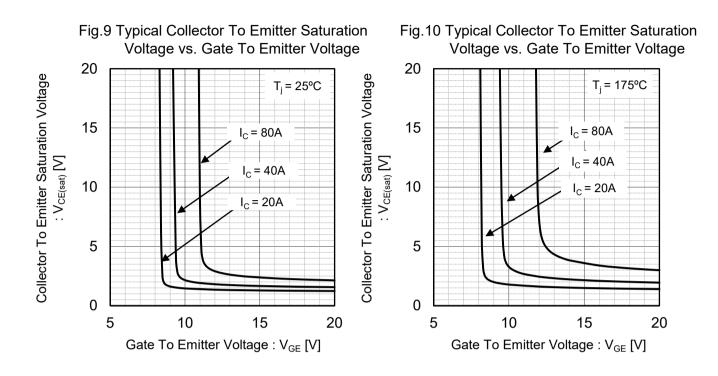


Fig.6 Typical Output Characteristics

Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature





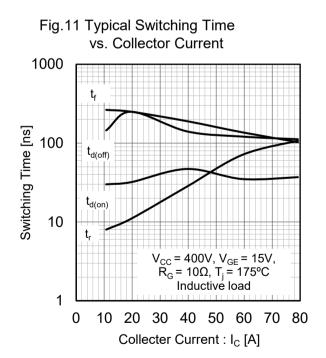
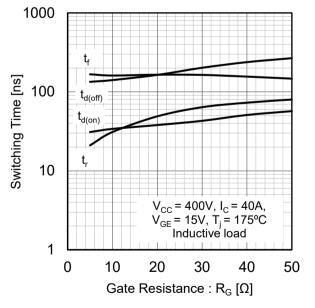
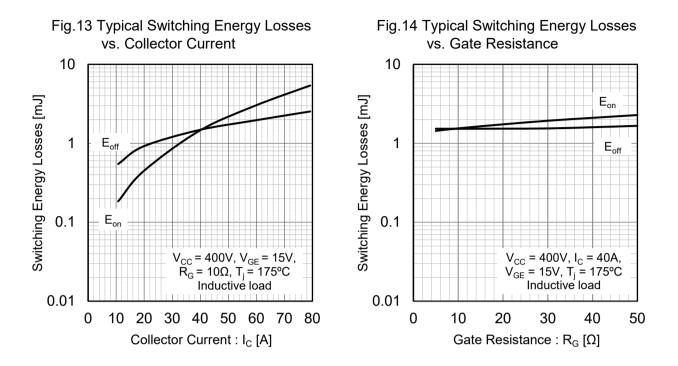
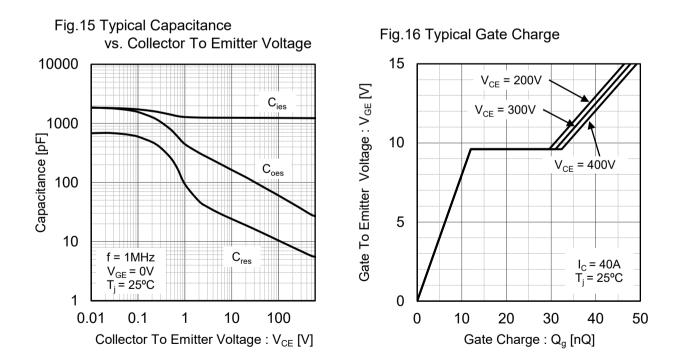


Fig.12 Typical Switching Time vs. Gate Resistance







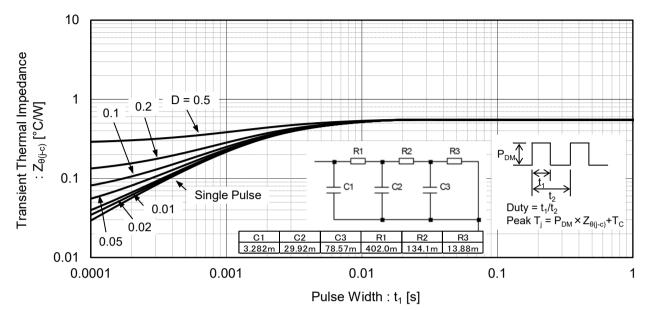


Fig.17 IGBT Transient Thermal Impedance

8/9



Inductive Load Switching Circuit and Waveform

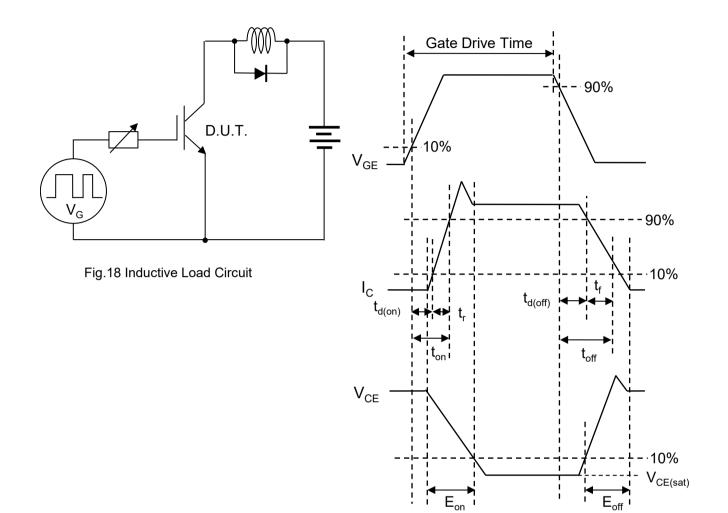


Fig.19 Inductive Load Waveform

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